

**DESCRIPTION**

This is a dual high radiance 660 nm visible and 895 nm infrared emitting LED Assembly, designed for medical ratio-metric measurements.

**FEATURES**

- Visible and infrared power emissions
- High Reliability
- Small surface mount ceramic substrate
- 2-Terminal Electrical connection

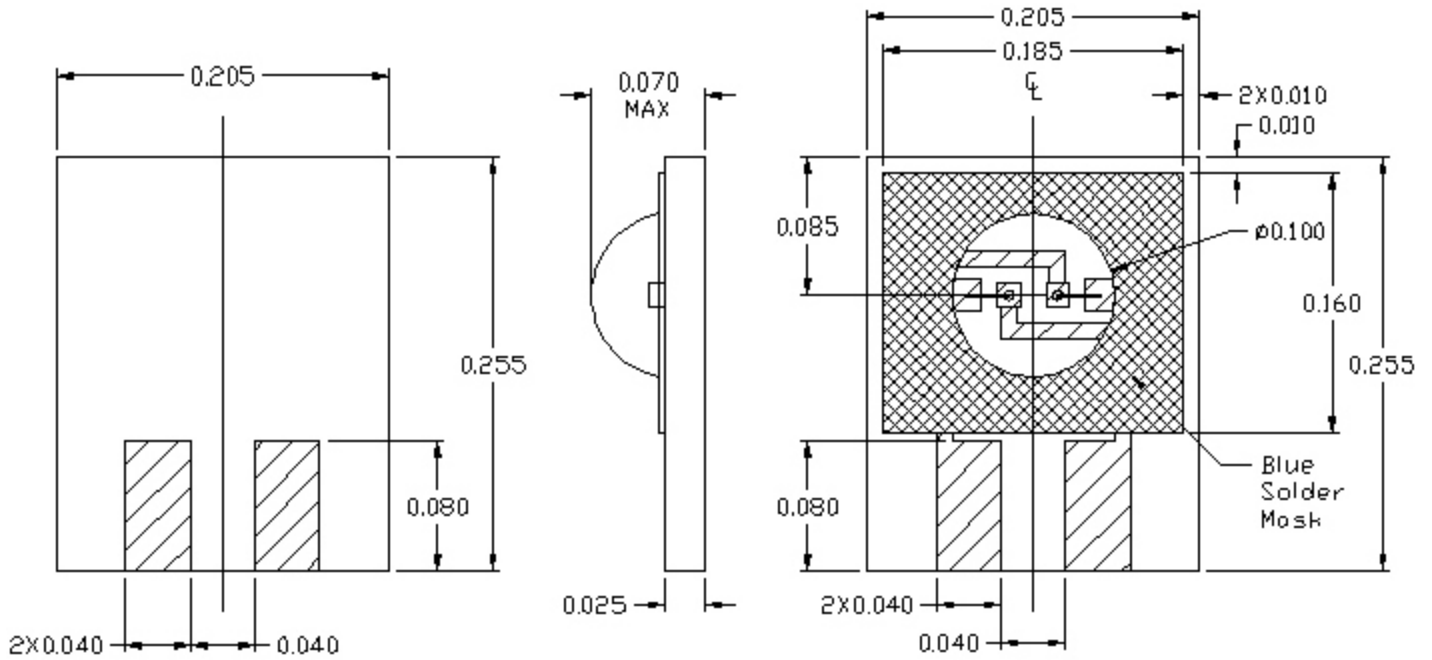
**ABSOLUTE MAXIMUM RATINGS**

- Storage temperature..... -40°C to +80°C
- Case operating temperature..... -40°C to +80°C
- Solder temperature..... 240°C, 3 seconds
- Reverse Voltage..... 5 Volts

**ELECTRO-OPTICAL CHARACTERISTICS (Case T = 25°C)**

PARAMETER	TEST CONDITION	SYMBOL	MIN	TYP	MAX	UNIT
Forward Voltage (660 nm)	If = 20 mA	V <sub>f1</sub>		1.8	2.4	Volts
Forward Voltage (895 nm)	If = 20 mA	V <sub>f2</sub>		1.3	1.7	Volts
Reverse Breakdown Voltage (660 nm)	I <sub>r</sub> = 10 μA	BVR	5			Volts
Reverse Breakdown Voltage (895 nm)	I <sub>r</sub> = 10 μA	BVR	5			Volts
Radiant Flux (660 nm)	If = 20 mA	P <sub>o1</sub>	1.5	1.9		mW
Radiant Flux (895 nm)	If = 20 mA	P <sub>o2</sub>	1.5	1.6		mW
Peak Wavelength (660 nm)	If = 20 mA	λ <sub>p</sub>	655	660	665	nm
Peak Wavelength (895 nm)	If = 20 mA	λ <sub>p</sub>	885	895	905	nm
Spectral Bandwidth (660 nm)	If = 20 mA, FWHM	Δλ		25		nm
Spectral Bandwidth (895 nm)	If = 20 mA, FWHM	Δλ		50		nm
Rise/Fall Time (660 nm)	If = 20 mA	tr/tf		0.8		μsec
Rise/Fall Time (895 nm)	If = 20 mA	tr/tf		0.8		μsec

**OUTLINE DIMENSIONS**



Tolerances are +/-0.005 inches, except as noted

**ELECTRICAL SCHEMATIC**

